

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	9558	257/440,460,323,293,417,431,436,440,458,464,465,466,467,470,930,E21.252,E27.008,E27.144,E29.324,E31.093.CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:49
L2	4	L1 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:50
L9	1	(US-5782974-\$).did.	USPAT	OR	ON	2005/09/01 21:51
L12	1	I9 and (plasma or gas or liquid or fluid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:56
S64	175156	"438"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:07
S65	323883	"257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:08
S66	28757	"374"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:08
S67	140536	"324"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:09
S68	221076	"73"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:09

S69	9	S64 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:28
S70	4	S65 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:29
S71	5	S66 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:18
S72	0	S67 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:18
S73	1	S68 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:32
S74	4014252	S69 or S70 or S71 or S72 or "70"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:19
S75	17	S69 or S70 or S71 or S72 or S73	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:19

S76	17	(US-20050037617-\$ or US-20040253759-\$ or US-20040121494-\$ or US-20040113080-\$ or US-20040058488-\$ or US-20040018746-\$).did. or (US-6821795-\$ or US-6617175-\$ or US-6480103-\$ or US-6384384-\$ or US-5782974-\$ or US-5549756-\$ or US-5367167-\$ or US-5288649-\$ or US-5180226-\$ or US-4558342-\$ or US-3777568-\$).did.	US-PGPUB; USPAT	OR	ON	2005/09/01 15:26
S77	8	(US-20030111605-\$ or US-20030148620-\$).did. or (US-6828172-\$ or US-6045257-\$ or US-5367167-\$ or US-5404125-\$ or US-5782974-\$ or US-5594248-\$). did.	US-PGPUB; USPAT	OR	ON	2005/09/01 15:29
S78	13	S64 and semiconductor and thermopile near detector and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:30
S79	2	S77 and semiconductor and thermopile near detector and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:30
S80	22	S64 and semiconductor and thermopile near4 (detector or sensor) and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:47
S81	8	S77 and semiconductor and thermopile near4 (detector or sensor) and infrared near2 radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:39
S82	8	S77 and thermopile near4 (detector or sensor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 15:46

S83	6	S77 and thermopile and (detector or sensor) and infrared and (target or material or sample)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 16:24
S84	8	S77 and thermopile and (detector or sensor) and infrared	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 21:53
S85	1	S83 and (controller or computer\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:00
S86	1	(US-5782974-\$).did.	USPAT	OR	ON	2005/09/01 17:00
S87	6	S84 and (gas or computer or solid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:23
S89	1	S86 and (gas or computer or solid or liquid or fluid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:14
S90	3	S84 and (fluid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:24
S91	1	S86 and (fluid or liquid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 17:24
S92	0	438/7,14,54,200,46,343,758,989	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:48

S93	5069	438/7,14,54,200,46,343,758,989. CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:49
S94	8	S93 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:51
S95	9558	257/440,460,323,293,417,431,436, 440,458,464,465,466,467,470,930, E21.252,E27.008,E27.144,E29.324, E31.093.CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:51
S96	4	S95 and semiconductor and thermopile near detector and infrared near2 radiation and ((process or processing) same (control\$3 or condition or parameter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/01 18:51